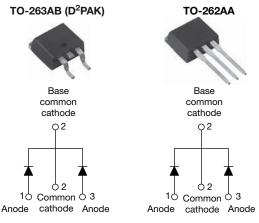
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RoHS

High Performance Schottky Rectifier, 2 x 15 A



VS-30CTQ...SPbF

VS-30CTQ...-1PbF

PRODUCT SUMMARY					
Package	TO-263AB (D ² PAK), TO-262AA				
I _{F(AV)}	2 x 15 A				
V _R	80 V to 100 V				
V _F at I _F	0.67 V				
I _{RM}	7 mA at 125 °C				
T _J max.	175 °C				
Diode variation	Common cathode				
E _{AS}	7.5 mJ				

FEATURES

- 175 °C T_J operation
- Center tap configuration
- Low forward voltage drop
- High frequency operation
- High purity, high temperature epoxy COMPLIANT encapsulation for enhanced mechanical HALOGEN strength and moisture resistance
 COMPLIANT
 COMPLIAN
- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

This center tap Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I _{F(AV)}	Rectangular waveform	30	A		
V _{RRM}		80/100	V		
I _{FSM}	t _p = 5 μs sine	850	A		
V _F	15 A _{pk} , T _J = 125 °C (per leg)	0.67	V		
TJ	Range	-55 to 175	°C		

VOLTAGE RATINGS					
PARAMETER	SYMBOL	VS-30CTQ080SPbF VS-30CTQ080-1PbF	VS-30CTQ100SPbF VS-30CTQ100-1PbF	UNITS	
Maximum DC reverse voltage	V _R	80	100	V	
Maximum working peak reverse voltage	V _{RWM}	80	100	V	

ABSOLUTE MAXIMUN	I RATING	S					
PARAMETER		SYMBOL	TEST COND	ITIONS	VALUES	UNITS	
Maximum average forward per device			$I_{F(AV)}$ 50 % duty cycle at T _C = 129 °C, rectangula		30		
current, see fig. 5	per leg	I _{F(AV)}	50% duty cycle at $1_{\rm C} = 129$ C	, rectangular wavelonn	15 A		
Maximum peak one cycle non-repetitive			5 µs sine or 3 µs rect. pulse	Following any rated load	850	A	
surge current per leg, see fig.		IFSM	10 ms sine or 6 ms rect. pulse	rect. pulse V _{RRM} applied 275			
Non-repetitive avalanche energ	gy per leg	E _{AS}	$T_{J} = 25 \ ^{\circ}C, I_{AS} = 0.50 \ A, L = 60$	mH	7.50	mJ	
Repetitive avalanche current p	er leg	I _{AR}	Current decaying linearly to zero Frequency limited by T _J maximu		0.50	А	

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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS
		15 A	T,I = 25 °C	0.86	V
Maximum forward voltage drop per leg See fig. 1	V _{FM} ⁽¹⁾	30 A	1j=25 0	1.05	
	¥FM (*)	15 A	T _{.I} = 125 °C	0.67	
		30 A	1j = 125 C	0.82	
Maximum reverse leakage current per leg	I _{RM} ⁽¹⁾	T _J = 25 °C	$V_{\rm B}$ = Rated $V_{\rm B}$	0.55	mA
See fig. 2	IRM \''	T _J = 125 °C	VR - naleu VR	7.0	
Maximum junction capacitance per leg	CT	$V_{R} = 5 V_{DC}$ (test signal range	ge 100 kHz to 1 MHz), 25 °C	500	pF
Typical series inductance per leg	L _S	Measured lead to lead 5 r	nm from package body	8.0	nH
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range		T _J , T _{Stg}		-55 to +175	°C
Maximum thermal resistance, junction to case per leg Maximum thermal resistance, junction to case per package		D	DC operation	3.25	°C/W
		R _{thJC}	De operation	1.63	0,10
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.50	
Approximate weight				2	g
Approximate weight				0.07	oz.
Mounting torque	minimum			6 (5)	kgf ⋅ cm
	maximum			12 (10)	(lbf · in)
Marking davias	Case style TO-263AB (D ² PAK) 30CTQ100S		Q100S		
Marking device			Case style TO-262AA	30CTC	100-1



VS-30CTQ...SPbF, VS-30CTQ...-1PbF Series

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80

100

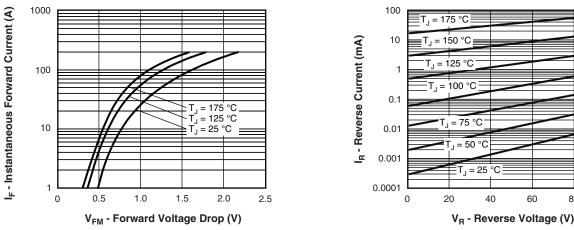
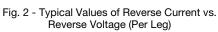


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)



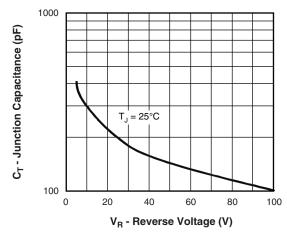
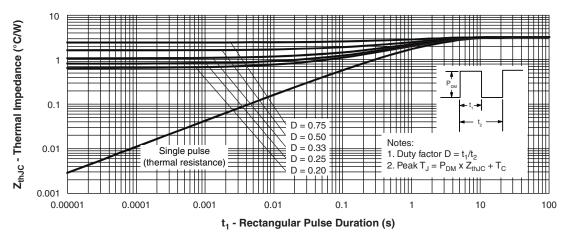


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)



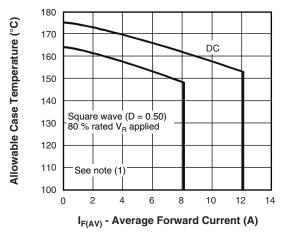


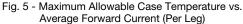
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VS-30CTQ...SPbF, VS-30CTQ...-1PbF Series

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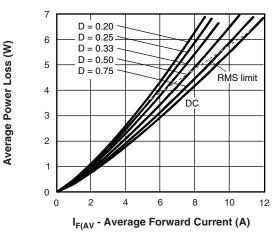


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

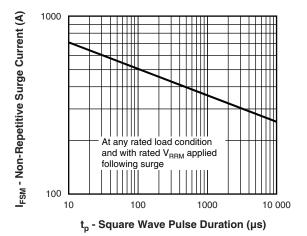
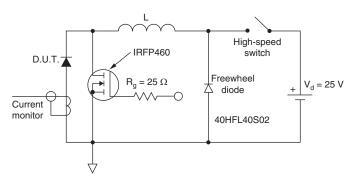


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)





Note

- ⁽¹⁾ Formula used: $T_C = T_J (Pd + Pd_{REV}) \times R_{thJC}$;
- $\begin{array}{l} \mathsf{Pd} = \mathsf{Forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \ \mathsf{x} \ \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{Inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \ \mathsf{x} \ \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{10} \ \mathsf{V} \end{array}$

Revision: 08-Dec-14

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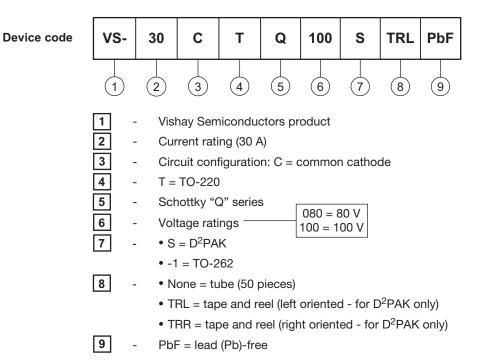
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ORDERING INFORMATION TABLE



ORDERING INFORMATION (Example)					
PREFERRED P/N	QUANTITY PER REEL	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION		
VS-30CTQ080SPBF	50	1000	Antistatic plastic tubes		
VS-30CTQ080STRRPBF	800	800	13" diameter plastic tape and reel		
VS-30CTQ080STRLPBF	800	800	13" diameter plastic tape and reel		
VS-30CTQ080-1PBF	50	1000	Antistatic plastic tubes		
VS-30CTQ090SPBF	50	1000	Antistatic plastic tubes		
VS-30CTQ090STRRPBF	800	800	13" diameter plastic tape and reel		
VS-30CTQ090STRLPBF	800	800	13" diameter plastic tape and reel		
VS-30CTQ090-1PBF	50	1000	Antistatic plastic tubes		
VS-30CTQ100SPBF	50	1000	Antistatic plastic tubes		
VS-30CTQ100STRRPBF	800	800	13" diameter plastic tape and reel		
VS-30CTQ100STRLPBF	800	800	13" diameter plastic tape and reel		
VS-30CTQ100-1PBF	50	1000	Antistatic plastic tubes		

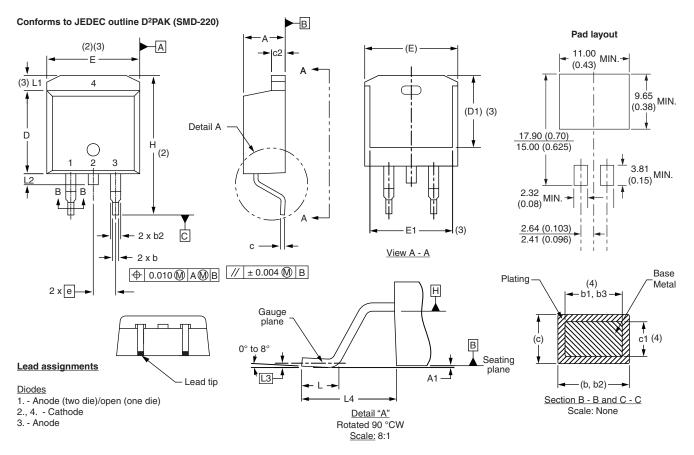
LINKS TO RELATED DOCUMENTS				
		www.vishay.com/doc?95046		
Dimensions	TO-262AA	www.vishay.com/doc?95419		
Part marking information		www.vishay.com/doc?95008		
Packaging information		www.vishay.com/doc?95032		

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D²PAK, TO-262



DIMENSIONS - D²PAK in millimeters and inches

SHA

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190	
A1	0.00	0.254	0.000	0.010	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
с	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2

SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.100	BSC	
Н	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	-	1.65	-	0.066	3
L2	1.27	1.78	0.050	0.070	
L3	0.25	BSC	0.010	BSC	
L4	4.78	5.28	0.188	0.208	

INCHES

MILLIMETERS

⁽⁷⁾ Outline conforms to JEDEC outline TO-263AB

Notes

 $^{(1)}\,$ Dimensioning and tolerancing per ASME Y14.5 M-1994 $\,$

⁽²⁾ Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

- $^{(3)}\,$ Thermal pad contour optional within dimension E, L1, D1 and E1
- ⁽⁴⁾ Dimension b1 and c1 apply to base metal only
- ⁽⁵⁾ Datum A and B to be determined at datum plane H
- ⁽⁶⁾ Controlling dimension: inch

Document Number: 95014 Revision: 31-Mar-09

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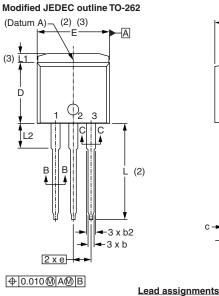
Outline Dimensions

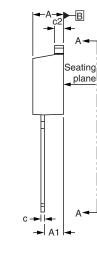
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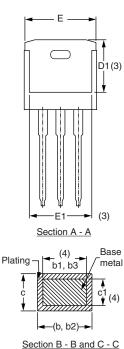
D²PAK, TO-262



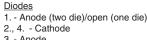
DIMENSIONS - TO-262 in millimeters and inches

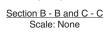






Lead tip





SYMBOL	MILLIMETERS		INCI	NOTES	
	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190	
A1	2.03	3.02	0.080	0.119	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.100	BSC	
L	13.46	14.10	0.530	0.555	
L1	-	1.65	-	0.065	3
L2	3.56	3.71	0.140	0.146	

Notes

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994

⁽²⁾ Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

⁽³⁾ Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

⁽⁵⁾ Controlling dimension: inches

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actual package outline

(6) Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum) and D1 (minimum) where dimensions derived the

3. - Anode



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